

Supporting Information

Photovoltaic-enhanced water splitting properties of low-temperature synthesis BiVO₄ photoanode films

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BVO-ITO photoanode films with different thicknesses were prepared by sol-gel spin coating method. The phase, element composition and oxygen evolution performance of the materials were analyzed. BVO photoanodes with a thickness of 90, 120, 150, 180 and 210 nm are represented by BVO-*x* (*x*=90, 120, 150, 180, 210), respectively.

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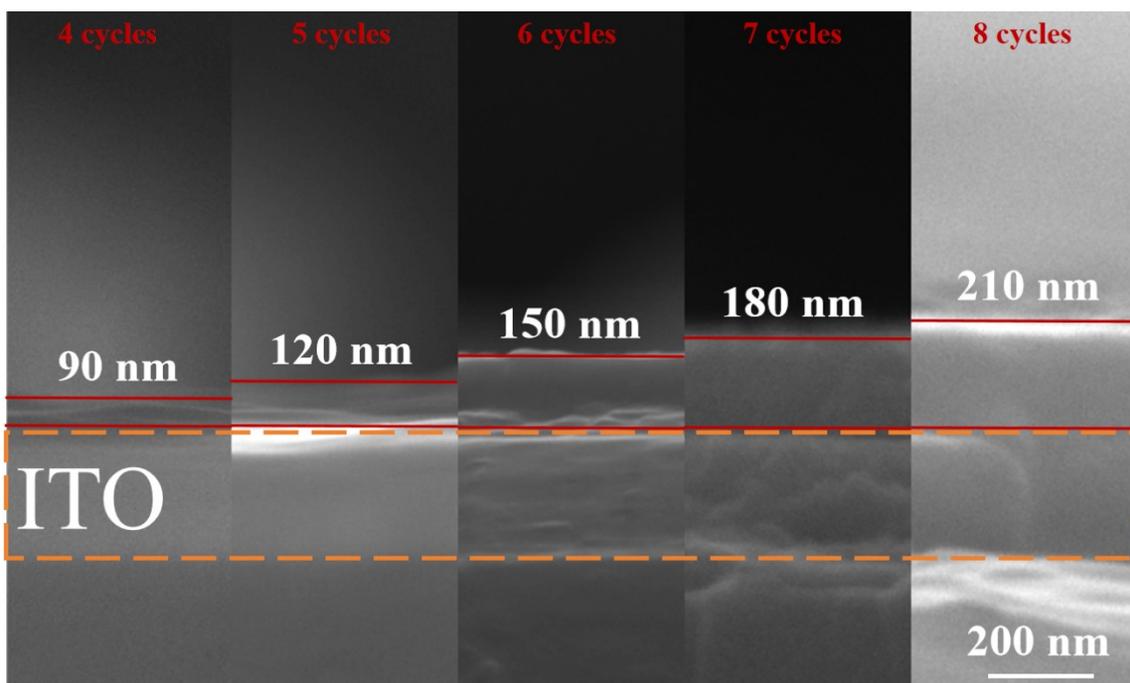


Fig. S1 Out-of-plane SEM image of BVO photoanodes with spin coating 4~8 cycles.

Fig. S2 Plot of $[ah\nu]^2$ as a function of $h\nu$ of BVO- x ($x=90, 120, 150, 180, 210$) photoanodes.

Fig. S3 Fine scanning XPS O 1s spectra of (a) BVO-90, (b) BVO-150, (c) BVO-180, (d) BVO-210 photoanodes.

Fig. S4 (a) $J-V$ curves and (b) $J-t$ curves (1.23 V vs RHE) of BVO- x ($x=90, 120, 150, 180, 210$) photoanodes under repeated AM-1.5G light on and off switching.

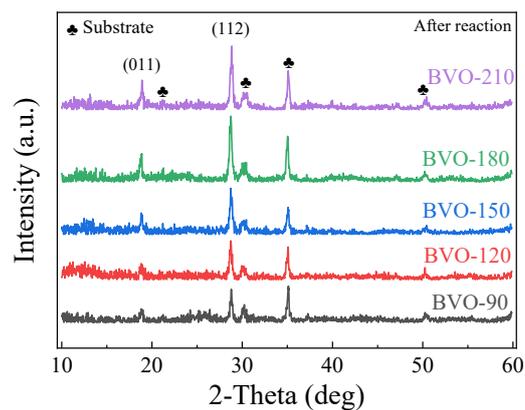


Fig. S5 XRD patterns of BVO- x ($x=90, 120, 150, 180, 210$) photoanodes after oxygen evolution reaction.

Fig. S6 Mott-Schottky plots of BVO- x ($x=90, 120, 150, 180, 210$) photoanodes.

Fig. S7 J - V curves of (a) BVO-90, (b) BVO-150, (c) BVO-180, (d) BVO-210 under dark and lights illumination (measured in two-electrode system).

Fig. S8 J - t curves of BVO- x ($x=90, 120, 150, 180, 210$) photoanodes under repeated (a) 365 nm, (b) 450 nm, (c) 520 nm light on and off switching (zero bias).